

Single Stage Fly-back & PFC Controller With Primary Side Control For LED Lighting

Features

- Primary side control eliminates the opto-coupler
- Valley turn-on of the primary MOSFET to achieve lower switching losses
- Power factor >0.95 @230VAC
- THD < 10% @230VAC
- Reliable short LED and Open LED protection
- Quick start up:<500ms
- Low start up current:15µA typical
- Package: SOT23-6, SOIC-8

Applications

LED Lighting

Descriptions

The DIO8650E is a single stage Fly-back and PFC controller targeting at LED lighting applications.

The DIO8650E is a primary side controller without applying any secondary feedback circuit for low cost, and drives the Fly-back converter in the quasi-resonant mode to achieve higher efficiency.

The DIO8650E keeps the Fly-back converter in constant on time operation to achieve high power factor.

This chip adopts special design to achieve quick start up and reliable protection for safety requirement.

Block Diagram

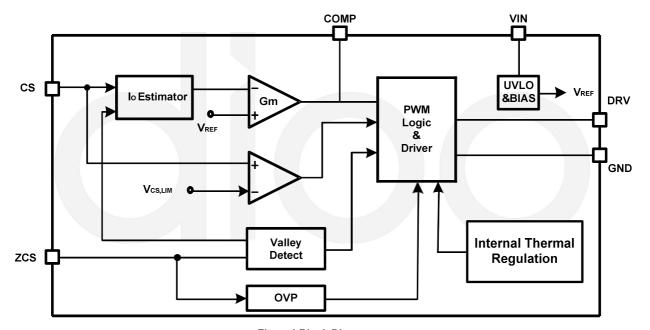


Figure1 Block Diagram



Ordering Information

Order Part Number	Top Marking		T _A	Package	
DIO8650ECST6	YW6E	Green	-40 to +125°C	SOT23-6	Tape & Reel, 3000
DIO8650ECS8	DIO8650E	Green	-40 to +125°C	SOIC-8	Tape & Reel, 2500

Pin Assignments

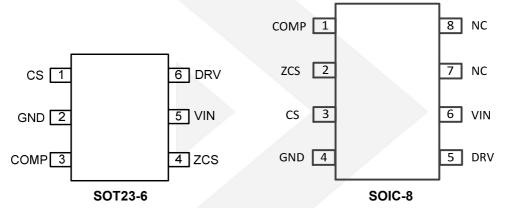


Figure 2 Pin Assignment (Top View)

Pin Definitions

Pin Name	Description
	Current sense pin. Connect this pin to the source of the primary switch. Connect the sense resistor
	across the source of the primary switch and the GND pin.
cs	(current sense resister Resistor: $R_{CS} = k \times \frac{V_{ref} \times N_{ps}}{I_{out}}$, k=0.167)
	Also this pin used to detect transformer and secondary is short or not.
GND	Ground pin
COMP	Loop compensation pin. Connect a RC network across this pin and ground to stabilize the control
COMP	loop.
	Inductor current zero-crossing detection pin. This pin receives the auxiliary winding voltage by a
	resister divider and detects the inductor current zero crossing point. This pin also provides over
ZCS	voltage protection and line regulation modification function simultaneously. If the voltage on this pin
	is above V _{ZCS,OVP} , the IC would enter over voltage protection mode. Good line regulation can be
	achieved by adjusting the upper resistor of the divider
VIN	Power supply pin. This pin also provides output over voltage protection along with ZCS pin.
DRV	Gate driver pin. Connect this pin to the gate of primary MOSFET.
NC	Not Connect.



Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Rating" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other condition beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maxim rating conditions for extended periods may affect device reliability.

Pa	rameter	Rating	Unit	
VIN, DRV		-0.3 to 33	V	
Supply Current I _{VIN}		15	mA	
ZCS		-0.3 to VIN+0.3	V	
CS, COMP		-0.3 to 5	V	
Power Dissipation, P _D @ T _A = 25°C	C, SOT23-6	0.6	W	
Package Thermal Resistance,	ӨЈА	170	2000	
SOT23-6	θ _{JC}	130	- °C/W	
Power Dissipation, P _D @ T _A = 25°C, SOIC-8		1.1	W	
Package Thermal Resistance,	ӨЈА	100	2000	
SOIC-8	θ _{JC}	50	- °C/W	
Storage Temperature Range		-65 to 150	°C	
Junction Temperature Range		150	°C	
Lead Temperature Range		260	°C	
ESD	HBM, JEDEC: JESD22-A114	2000	V	
EOD	MM, JEDEC: JESD22-A115	200		

Recommend Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended Operating conditions are specified to ensure optimal performance to the datasheet specifications. DIOO does not Recommend exceeding them or designing to Absolute Maximum Ratings.

Parameter	Rating	Unit
Supply Voltage	9.5 to 27	V
Ambient Temperature Range	-40 to 125	°C



Electrical Characteristics

 V_{IN} = 12V, T_A = 25°C, unless otherwise specified.

Symbol	Paramete	er	Test Conditions	Min	Тур	Max	Un
$V_{\text{VIN,ON}}$	VIN turn-on threshold				25.3		V
$V_{\text{VIN,OFF}}$	VIN turn-off threshold				8.5		V
$V_{\text{VIN,OVP}}$	VIN OVP voltage				30		٧
I _{ST}	Start up Current		V _{VIN} < V _{IN,OFF}		15		μA
I _{VIN_OVP}	Shunt current in OVP n	node	After V _{VIN} >V _{VIN,OVP} , then set VIN=15V	1.6	2	2.5	m/
IQ	Quiescent Current		No switching		0.26		m/
I _{VIN}	Operation current		C _L =100pF,f=15kHz		0.36		m/
Error Amplifier Se	ection						
V_{REF}	Internal reference volta	ge		0.294	0.3	0.306	V
CS pin Section	•				•	•	l
V_{ZCS} , ovp	ZCS pin OVP voltage the	ZCS pin OVP voltage threshold			1.5		V
V _{FAST_ST}	Fast start up threshold				0.55		V
Current Sense Se	ction(Source PIN of integ	rated MOSFE		•	•	•	I
$V_{\text{CS.LMT}}$	Current limit reference	voltage			0.45		V
K ₂	CC Feed forward coeffi	cient			0.1		
R _{K2}	CC Feed forward resistor R _{K2}				340		Ω
PWM Section	•			•	•	•	•
T _{ON.MAX}	Max on time		COMP high clamp		15.7		μs
T_LEB	Leading edge blanking	time			300		ns
$T_{OFF,MAX}$	Max OFF time				151		με
T _{LEB.ZCD}	ZCD Blanking Time	/	After turn off		2		με
f _{MAX}	Maximum switching fre	quency			115		kH
Sate Driver					•		
V _{GATE_CLAMP}	Output Clamp Voltage		V _{CC} =20V		12		V
T _{RISING}	rising time from 10% to	90%	C _{LOAD} =1nF		410		ns
T _{FALLING}	falling time from 90% to 10%		C _{LOAD} =1nF		50		ns
hermal Section					_	_	
T _{SD}	Thermal Shutdown Ter	nnerature			150		°C



Typical Application

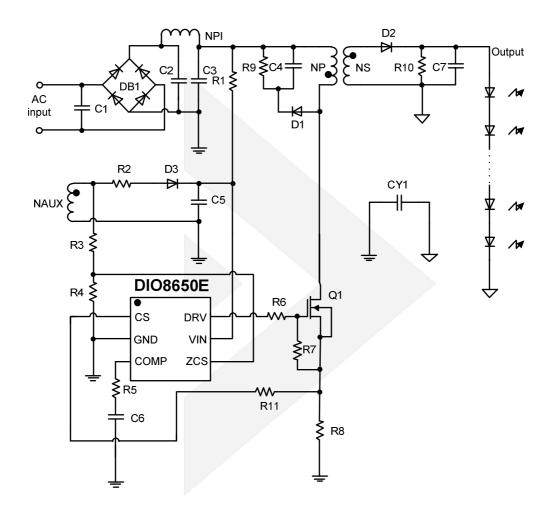


Figure 3 Typical fly-back application



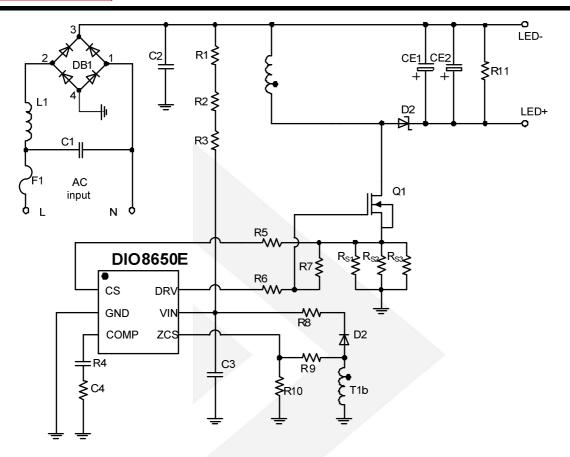


Figure 4 Typical buck-boost application

Application Information

Start up

After AC or DC supply is powered on, the capacitor C_{VIN} across VIN and GND pin is charged up by BUS voltage through a start up resistor R_{ST} . Once V_{VIN} rises up to V_{VIN-ON} , the internal blocks start to work and PWM output is enabled.

Shut down

After AC supply or DC BUS is powered off, the energy stored in the BUS capacitor will be discharged. When the auxiliary winding of Fly-back transformer can't supply enough energy to VIN pin, V_{VIN} will drop down. Once V_{VIN} is below $V_{VIN-OFF}$, the IC will stop working and V_{COMP} will be discharged to zero.

Primary-side constant-current control

Primary side control is applied to eliminate secondary feedback circuit or opto-coupler, which reduces the circuit cost.



Quasi-Resonant Operation

QR mode operation provides low turn-on switching losses for Fly-back converter.

Over Voltage Protection (OVP) & Open LED Protection (OLP)

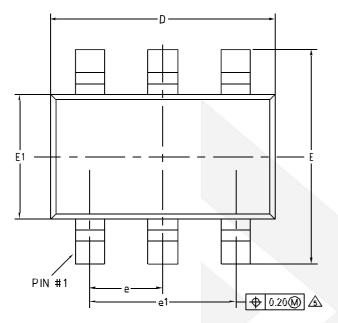
The output voltage is reflected by the auxiliary winding voltage of the Fly-back transformer, and both ZCS pin and VIN pin provide over voltage protection function. When the load is null or large transient happens, the output voltage will exceed the rated value. When V_{VIN} exceeds $V_{VIN,OVP}$ or V_{ZCS} exceeds $V_{ZCS,OVP}$, the over voltage protection is triggered and the IC will discharge V_{VIN} by an internal current source $I_{VIN,OVP}$. Once V_{VIN} is below $V_{VIN,OFF}$, the IC will shut down and be charged again by BUS voltage through start up resistor. If the overvoltage condition still exists, the system will operate in hiccup mode.

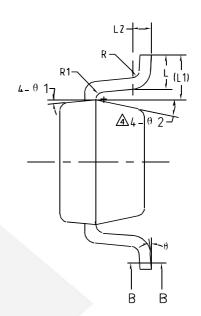
Short Circuit Protection (SCP)

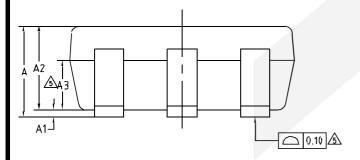
When the output is shorted to ground, the output voltage is clamped to zero. The voltage of the auxiliary winding is proportional to the output winding, so valley signal cannot be detected by ZCS. Without valley detection, MOSFET cannot be turned ON until maximum off time $t_{OFF,MAX}$ is matched. If MOSFET is turned ON by $t_{OFF,MAX}$ 64 times continuously, IC will be shut down and enter into hiccup mode. If the output voltage is not low enough to disable valley detection in short condition, V_{VIN} will dropdown without auxiliary winding supply. Once V_{VIN} is below $V_{VIN,OFF}$, the IC will shut down and be charged again by the BUS voltage through the start up resistor. If the short circuit condition still exists, the system will operate in hiccup mode.

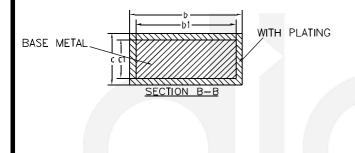


Physical Dimensions: SOT-23-6





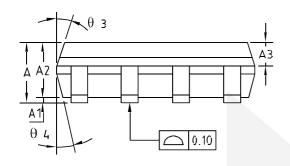


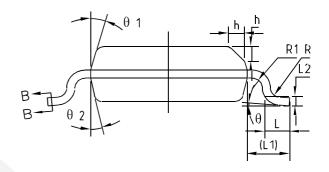


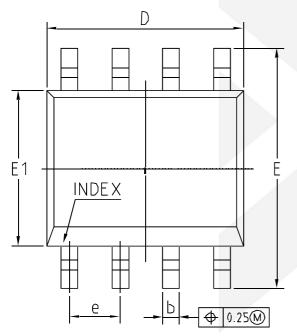
COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)					
Symbol	MIN	NOM	MAX		
A	-	-	1.25		
A1	0	-	0.15		
A2	1.00	1.10	1.20		
A3	0.60	0.65	0.70		
b	0.36	-	0.50		
b1	0.36	0.38	0.45		
С	0.14	-	0.20		
c1	0.14	0.15	0.16		
D	2.826	2.926	3.026		
E	2.60	2.80	3.00		
E1	1.526	1.626	1.726		
е	0.90	0.95	1.00		
e1	1.80	1.90	2.00		
L	0.35	0.45	0.60		
L1	0.59REF				
L2	0.25BSC				
R	0.10	-	-		
R1	0.10	-	0.25		
Θ	0°	-	8°		
Θ1	3°	5°	7°		
Θ2	6°	·	14°		

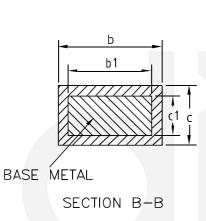


Physical Dimensions: SOIC-8









(UNITS OF MEASURE=MILLIMETER)					
Symbol	MIN	NOM	MAX		
Α	1.35	1.55	1.75		
A1	0.10	0.15	0.25		
A2	1.25	1.40	1.65		
А3	0.50	0.60	0.70		
b	0.38	-	0.51		
b1	0.37	0.42	0.47		
С	0.17	ı	0.25		
c1	0.17	0.20	0.23		
D	4.80	4.90	5.00		
E	5.80	6.00	6.20		
E1	3.80	3.90	4.00		
е	1.27BSC				
L	0.45	0.60	0.80		
L1	1.04REF				
L2		0.25BSC			
R	0.07	ı	-		
R1	0.07	-	-		
h	0.30	0.40	0.50		
Θ	0° -		8°		
Θ1	15° 17°		19°		
Θ2	11° 13° 15°				
Θ3	15° 17° 19°				
Θ4	11° 13° 15°				



CONTACT US

Dioo is a professional design and sales corporation for high-quality and performance analog semiconductors. The company focuses on industry markets, such as, cell phone, handheld products, laptop, and medical equipment and so on. Dioo's product families include analog signal processing and amplifying, LED drivers and charger IC. Go to http://www.dioo.com for a complete list of Dioo product families.

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